

# High-Frequency Amplifier Transistor(11V, 50mA, 3.2GHz)

### 2SC5662 / 2SC4726 /2SC4083 / 2SC3838K

#### Features

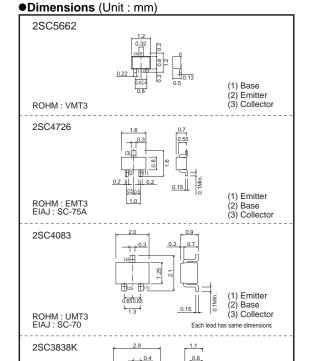
- 1) High transition frequency. (Typ. ft= 3.2GHz)
- 2) Small rbb' Cc and high gain. (Typ. 4ps)
- 3) Small NF.

#### ●Packaging specifications and hFE

Type	2SC5662	2SC4726	2SC4083	2SC3838K
Package	VMT3	EMT3	UMT3	SMT3
hfe	NP	NP	NP	NP
Marking	Marking AD		1D	AD
Code	T2L	TL	T106	T146
Basic ordering unit (pieces)	8000	3000	3000	3000

● Absolute maximum ratings (Ta=25°C)

Para	Symbol	Limits	Unit				
Collector-base voltage		Vсво	20	V			
Collector-emitter voltage		Vceo	11	V			
Emitter-base voltage		VEBO	3	V			
Collector current		Ic	50	mA			
Collector power	Collector power 2SC5662, 2SC4726		0.15	W			
dissipation	2SC4083, 2SC3838K	Pc	0.2	] vv			
Junction temperature		Tj	150	°C			
Storage temperature		Tstg	-55 to +150	°C			



(3)

(1) Emitter (2) Base (3) Collector

(2)

ROHM : SMT3 EIAJ : SC-59

#### ● Absolute maximum ratings (Ta=25°C)

	Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Collector-base	Collector-base breakdown voltage		20	_	-	V	Ic = 10μA
Collector-emitte	er breakdown voltage	BVceo	11	_	-	V	Ic = 1mA
Emitter-base br	eakdown voltage	ВУЕВО	3	-	-	V	Iε = 10μA
Collector cutoff	current	Ісво	-	-	0.5	μА	Vcb = 10V
Emitter cutoff c	urrent	Ієво	-	-	0.5	μА	VEB = 2V
Collector-emitte	er saturation voltage	VCE(sat)	-	-	0.5	V	Ic/I <sub>B</sub> = 10mA/5mA
DC current transfer ratio	2SC5662, 2SC4726, 2SC4083, 2SC3838K	hfE	56	_	180	-	Vce/lc = 10V/5mA
Transition frequ	iency	f⊤	1.4	3.2	-	GHz	Vce = 10V , Ie = -10mA , f = 500MHz
Output capacita	ance	Cob	_	0.8	1.5	pF	Vcb = 10V , IE = 0A , f = 1MHz
Collector-base time constant		гьь'∙Сс	-	4	12	ps	VcB = 10V , Ic = 10mA , f = 31.8MHz
Noise factor		NF	_	3.5	_	dB	$V_{CE} = 6V$ , $I_{C} = 2mA$ , $f = 500MHz$ , $Rg = 50\Omega$

This product might cause chip aging and breakdown under the large electrified environment. Please consider to design ESD protection circuit.

#### •Electric characteristics curves

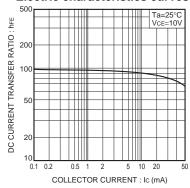


Fig.1 DC current gain vs. collector current

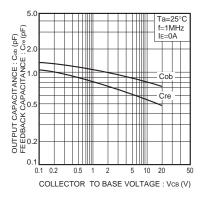


Fig.4 Capacitance vs. reverse bias voltage

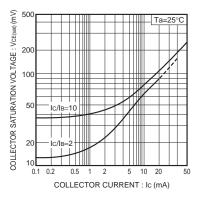


Fig.2 Collector-emitter saturation voltage vs. collector current

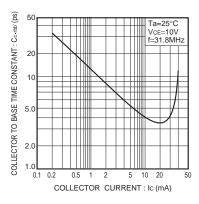


Fig.5 Collector to base time constance vs. collector current

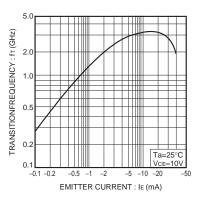


Fig.3 Gain bandwidth product vs. emitter current

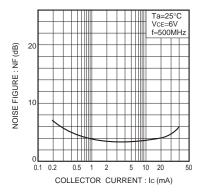


Fig.6 Noisfactor vs. collector current characteristics

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